









SN74AVC4T245-Q1 SCES792C - NOVEMBER 2009 - REVISED FEBRUARY 2024

SN74AVC4T245-Q1 Automotive 4-Bit Dual-Supply Bus Transceiver with Configurable Voltage Translation and 3-State Outputs

1 Features

- Qualified for automotive applications
- AEC-Q100 qualified with the following results:
 - Device temperature grade 1: –40°C to 125°C ambient operating temperature range
 - Device HBM ESD classification level H3B (JESD 22 A114-A)
 - Device CDM ESD classification level C5 (JESD 22 C101)
- Function safety capable
- Control input V_{IH} and V_{IL} levels are referenced to V_{CCA} voltage
- Fully configurable dual-rail design allows each port to operate over the full 1.2V to 3.6V power-supply
- I/Os are 4.6V tolerant
- I_{off} supports partial power-down-mode operation
- Maximum data rates:
 - 380Mbps (1.8V to 3.3V translation)
 - 200Mbps (<1.8V to 3.3V translation)
 - 200Mbps (translate to 2.5V or 1.8V)
 - 150Mbps (translate to 1.5V)
 - 100Mbps (translate to 1.2V)
- Latch-up performance exceeds 100mA per JESD 78, Class II

2 Applications

- **Telematics**
- Cluster
- Head unit
- Navigation systems

3 Description

This 4-bit non-inverting bus transceiver uses two separate configurable power-supply rails. The A port is designed to track V_{CCA}. V_{CCA} accepts any supply voltage from 1.2V to 3.6V. The B port is designed to track V_{CCB}. V_{CCB} accepts any supply voltage from 1.2V to 3.6V. The SN74AVC4T245-Q1 is optimized to operate with V_{CCA}/V_{CCB} set at 1.4V to 3.6V. It is operational with V_{CCA}/V_{CCB} as low as 1.2V. This allows for universal low-voltage bidirectional translation between any of the 1.2V, 1.5V, 1.8V, 2.5V, and 3.3V voltage nodes.

SN74AVC4T245-Q1 The is designed for asynchronous communication between two data buses. The logic levels of the direction-control (DIR) input and the output-enable (OE) input activate either the B-port outputs or the A-port outputs or place both output ports into the high-impedance mode. The device transmits data from the A bus to the B bus when the B-port outputs are activated, and from the B bus to the A bus when the A-port outputs are activated. The input circuitry on both A and B ports is always active and must have a logic HIGH or LOW level applied to prevent excess I_{CC} and I_{CC7}.

The SN74AVC4T245-Q1 is designed so that the control pins (1DIR, 2DIR, 1 \overline{OE} , and 2 \overline{OE}) are supplied by V_{CCA}.

This device is fully specified for partial-power-down applications using Ioff. The Ioff circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The design of the V_{CC} isolation feature places both ports in the high-impedance state if either V_{CC} input is at GND.

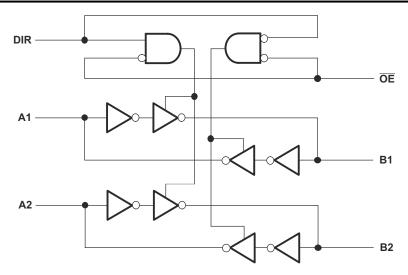
To place the device in the high-impedance state during power up or power down, tie \overline{OE} to V_{CC} through a pullup resistor; the current-sinking capability of the driver determines the minimum value of the resistor.

Package Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾					
	RGY (VQFN, 16)	4mm × 3.5mm					
SN744V/C4T245 O1	PW (TSSOP, 16)	5mm × 6.4mm					
SN74AVC4T245-Q1	BQB (WQFN, 16)	3.5mm × 2.5mm					
	DYY (SOT, 16)	4.2mm × 2mm					

- (1) For more information, see Section 11
- The package size (length × width) is a nominal value and includes pins, where applicable.





Logic Diagram (Positive Logic) for 1/2 of SN74AVC4T245-Q1



Table of Contents

1 Features	7.1 Overview	17
2 Applications	7.2 Functional Block Diagram	17
3 Description	7.3 Feature Description	18
4 Pin Configuration and Functions3	7.4 Device Functional Modes	18
5 Specifications5	8 Application and Implementation	19
5.1 Absolute Maximum Ratings5	8.1 Application Information	19
5.2 ESD Ratings5	8.2 Typical Application	19
5.3 Recommended Operating Conditions5	8.3 Power Supply Recommendations	
5.4 Thermal Information6	8.4 Layout	21
5.5 Electrical Characteristics7	9 Device and Documentation Support	22
5.6 Switching Characteristics: V _{CCA} = 1.2V8	9.1 Documentation Support	22
5.7 Switching Characteristics, V _{CCA} = 1.5V ± 0.1V9	9.2 Receiving Notification of Documentation Updates	22
5.8 Switching Characteristics: V _{CCA} = 1.8V ± 0.15V10	9.3 Support Resources	22
5.9 Switching Characteristics: V _{CCA} = 2.5V ± 0.2V10	9.4 Trademarks	22
5.10 Switching Characteristics: V _{CCA} = 3.3V ± 0.3V 11	9.5 Electrostatic Discharge Caution	22
5.11 Operating Characteristics13	9.6 Glossary	22
5.12 Typical Characteristics14	10 Revision History	22
6 Parameter Measurement Information16	11 Mechanical, Packaging, and Orderable	
7 Detailed Description17	Information	23

4 Pin Configuration and Functions

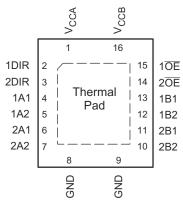


Figure 4-1. RGY Package 16-Pin VQFN With Exposed Thermal Pad (Top View)

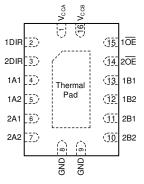


Figure 4-3. BQB/WBQB Package, 16-Pin WQFN (Transparent Top View)

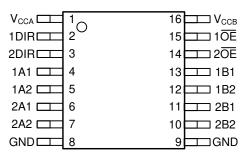


Figure 4-2. PW Package, 16-Pin TSSOP (Top View)

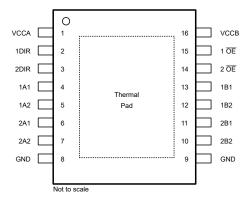


Figure 4-4. DYY Package, 16-Pin SOT (Top View)



Table 4-1. Pin Functions

Р	IN	TYPE(1)	DESCRIPTION
NAME	NO.	1 ITPE\"	DESCRIPTION
1A1	4	I/O	Input/output 1A1. Referenced to V _{CCA} .
1A2	5	I/O	Input/output 1A2. Referenced to V _{CCA} .
1B1	13	I/O	Input/output 1B1. Referenced to V _{CCB} .
1B2	12	I/O	Input/output 1B2. Referenced to V _{CCB} .
1DIR	2	I	Direction-control input for 1 ports
1 ŌE	15	I	3-state output-mode enable. Pull $\overline{\text{OE}}$ high to place '1' outputs in 3-state mode. Referenced to V _{CCA} .
2A1	6	I/O	Input/output 2A1. Referenced to V _{CCA} .
2A2	7	I/O	Input/output 2A2. Referenced to V _{CCA} .
2B1	11	I/O	Input/output 2B1. Referenced to V _{CCB} .
2B2	10	I/O	Input/output 2B2. Referenced to V _{CCB} .
2DIR	3	I	Direction-control input for 2 ports
2 OE	14	I	3-state output-mode enable. Pull $\overline{\text{OE}}$ high to place '2' outputs in 3-state mode. Referenced to V _{CCA} .
GND	8, 9	_	Ground
V _{CCA}	1	I	A-port power supply voltage. 1.2V ≤ V _{CCA} ≤ 3.6V
V _{CCB}	16	I	B-port power supply voltage. 1.2V ≤ V _{CCB} ≤ 3.6V
Thermal pad	d	_	The exposed thermal pad must be connected as a secondary GND or be left electrically open.

⁽¹⁾ I = input, O = output



5 Specifications

5.1 Absolute Maximum Ratings

over operating ambient temperature range (unless otherwise noted) (1)

			MIN	MAX	UNIT
V _{CCA} V _{CCB}	Supply voltage		-0.5	4.6	V
		I/O ports (A port)	-0.5	4.6	
V_{I}	Input voltage ⁽²⁾	I/O ports (B port)	-0.5	4.6	V
		Control inputs	-0.5	4.6	
\ /	Voltage applied to any output in the high-impedance or	A port	-0.5	4.6	V
Vo	power-off state ⁽²⁾	B port	-0.5	4.6	V
\/	Voltage applied to any output in the high or law state(2) (3)	A port	-0.5	V _{CCA} + 0.5	V
Vo	Voltage applied to any output in the high or low state ^{(2) (3)}	B port	-0.5	V _{CCB} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		– 50	mA
I _{OK}	Output clamp current	V _O < 0		– 50	mA
Io	Continuous output current			±50	mA
	Continuous current through V _{CCA} , V _{CCB} , or GND			±100	mA
T _{stg}	Storage temperature		-65	150	°C

⁽¹⁾ Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

5.2 ESD Ratings

			VALUE	UNIT
		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	±8000	
V _(ESD)	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	±1000	V
		Machine model (C101)	±150	

⁽¹⁾ JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

			V _{CCI}	V _{cco}	MIN	MAX	UNIT
V_{CCA}	Supply voltage				1.2	3.6	V
V _{CCB}	Supply voltage				1.2	3.6	V
			1.2V to 1.95V		V _{CCI} × 0.65		
V _{IH}	High-level	nput voltage	1.95V to 2.7V		1.6		V
	mpat voltago		2.7V to 3.6V		2		
			1.2V to 1.95V			V _{CCI} × 0.35	
V _{IL}	Low-level input voltage	Low-level Data inputs ⁽¹⁾	1.95V to 2.7V			0.7	V
	mpat voltago		2.7V to 3.6V			0.8	
			1.2V to 1.95V		V _{CCA} × 0.65		
V _{IH}	3	DIR (referenced to V _{CCA}) ⁽²⁾	1.95V to 2.7V		1.6		V
		(I or	2.7V to 3.6V		2		

⁽²⁾ The input voltage and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

⁽³⁾ The output positive-voltage rating may be exceeded up to 4.6V maximum if the output current rating is observed.

⁽²⁾ JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.



5.3 Recommended Operating Conditions (continued)

			V _{CCI}	V _{cco}	MIN	MAX	UNIT
			1.2V to 1.95V		V	/ _{CCA} × 0.35	
V _{IL}	Low-level input voltage	DIR (referenced to V _{CCA}) ⁽²⁾	1.95V to 2.7V			0.7	V
	mpat voltage	(Totoloneou to VCCA)	2.7V to 3.6V			0.8	
VI	Input voltage				0	3.6	V
\/	Output valtage	Active state			0	V _{cco}	V
Vo	Output voltage	3-state			0	3.6	v
		'		1.2V		-3	
				1.4V to 1.6V		-6	
I _{OH}	High-level output c	igh-level output current		1.65V to 1.95V		-8	mA
				2.3V to 2.7V		-9	
				3V to 3.6V		-12	
				1.1V to 1.2V		3	
				1.4V to 1.6V		6	
I _{OL}	Low-level output co	urrent		1.65V to 1.95V		8	mA
				2.3V to 2.7V		9	
				3V to 3.6V		12	
Δt/Δν	Input transition rise	or fall rate				5	ns/V
T _A	Operating ambient	temperature			-40	125	°C

5.4 Thermal Information

			SN74AVC	4T245-Q1		
	THERMAL METRIC ⁽¹⁾	RGY (VQFN)	PW (TSSOP)	BQB (WQFN)	DYY (SOT)	UNIT
		16 PINS	16 PINS	16 PINS	16 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	37.5	101.8	80.8	163.4	°C/W
R _{0JC(top)}	Junction-to-case (top) thermal resistance	54.5	37.2	77.9	90.0	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	15.6	60.6	50.7	93.1	°C/W
ΨЈТ	Junction-to-top characterization parameter	0.5	1.6	7.4	10.9	°C/W
Ψ _{JB}	Junction-to-board characterization parameter	15.8	60.0	50.6	92.1	°C/W
R ₀ JC(bot)	Junction-to-case (bottom) thermal resistance	3.5	N/A	28.4	N/A	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report (SPRA953).

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⁽¹⁾ For V_{CCI} values not specified in the data sheet, V_{IH} min = $V_{CCI} \times 0.7$ V, V_{IL} max = $V_{CCI} \times 0.3$ V (2) For V_{CCI} values not specified in the data sheet, V_{IH} min = $V_{CCA} \times 0.7$ V, V_{IL} max = $V_{CCA} \times 0.3$ V



5.5 Electrical Characteristics

over recommended operating ambient temperature range (unless otherwise noted)

PA	RAMETER	TEST CONI	DITIONS	V _{CCA}	V _{CCB}	T _A	MIN	TYP	MAX	UNIT
		I _{OH} = -100μA		1.2V to 3.6V	1.2V to 3.6V	T _A = -40°C to 125°C	V _{CCO} - 0.2			
		I _{OH} = -3mA		1.2V	1.2V	T _A = 25°C		0.95		
		I _{OH} = -6mA		1.4V	1.4V	T _A = -40°C to 125°C	1.05			
V _{OH}		I _{OH} = -8mA	V _I = V _{IH}	1.65V	1.65V	T _A = -40°C to 125°C	1.2			V
		I _{OH} = -9mA		2.3V	2.3V	T _A = -40°C to 125°C	1.75			
		I _{OH} = -12mA		3V	3V	T _A = -40°C to 125°C	2.3			
		I _{OL} = 100μA		1.2V to 3.6V	1.2V to 3.6V	T _A = -40°C to 125°C			0.2	
		I _{OL} = 3mA		1.2V	1.2V	T _A = 25°C		0.25		
V_{OL}	I _{OL} = 6mA		1.4V	1.4V	T _A = -40°C to 125°C			0.35		
	I _{OL} = 8mA	V _I = V _{IL}	1.65V	1.65V	T _A = -40°C to 125°C			0.45	V	
	I _{OL} = 9mA		2.3V	2.3V	T _A = -40°C to 125°C			0.55		
		I _{OL} = 12mA		3V	3V	T _A = -40°C to 125°C			0.7	
	Control	1.2V to 1.2V to T _A = 25°C		±0.025	±0.25					
I ⁽¹⁾	inputs	$V_I = V_{CCA}$ or GNE)	3.6V	3.6V	T _A = -40°C to 125°C			±1.5	μA
					0V to	T _A = 25°C		±0.1	±1	
	A or B port	V_1 or $V_0 = 0$ to 3.	6\/	0V	3.6V	T _A = -40°C to 125°C			±5	μA
off	A of B port	V 01 V ₀ = 0 to 3.	o v	0V to	to	T _A = 25°C		±0.1	±1	ļ , , ,
				3.6V	0V	T _A = -40°C to 125°C			±5	
		V _O = V _{CCO} or GN	חו			T _A = 25°C		±0.5	±2.5	
OZ	A or B port	$V_I = V_{CCI}$ or GND	$\overline{OE} = V_{IH}$	3.6V	3.6V	T _A = -40°C to 125°C			±5	μA
				1.2V to 3.6V	1.2V to 3.6V	T _A = -40°C to 125°C			8	
					0V to	T _A = 25°C			-2	
CCA ⁽	1)	$V_I = V_{CCI}$ or GND	, I _O = 0	0V	3.6V	T _A = -40°C to 125°C			-11	μA
				0V to 3.6V	0V	T _A = -40°C to 125°C			8	
				1.2V to 3.6V	1.2V to 3.6V	T _A = -40°C to 125°C			8	
I _{CCB} ⁽¹⁾	$V_1 = V_{CCI}$ or GND, $I_0 = 0$, I _O = 0	0V	0V to 3.6V	T _A = -40°C to 125°C			8	μA	
			-	0\/ to		T _A = 25°C			-2	
				0V to 3.6V 0V	0V	T _A = -40°C to 125°C			-11	
CCA +	· I _{CCB}	V _I = V _{CCI} or GND	, I _O = 0	1.2V to 3.6V	1.2V to 3.6V	T _A = -40°C to 125°C			16	μA

5.5 Electrical Characteristics (continued)

over recommended operating ambient temperature range (unless otherwise noted)

PAF	RAMETER	TEST CONDITIONS	V _{CCA}	V _{CCB}	T _A	MIN	TYP	MAX	UNIT
	Control				T _A = 25°C		3.5	4.5	
Ci	inputs	V _I = 3.3V or GND	3.3V	3.3V	T _A = -40°C to 125°C			7	pF
					T _A = 25°C		6		
C _{io}	A or B port	V _O = 3.3V or GND	3.3V	3.3V	T _A = -40°C to 125°C				pF

All unused data inputs of the device must be held at V_{CCI} or GND for proper device operation. See the TI application report, Implications of Slow or Floating CMOS Inputs, SCBA004.

5.6 Switching Characteristics: V_{CCA} = 1.2V

over recommended operating ambient temperature range, V_{CCA} = 1.2V (unless otherwise noted) (see Figure 6-1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB}	ТҮР	UNIT
			V _{CCB} = 1.2V	3.4	
			V _{CCB} = 1.5V ± 0.1V	2.9	
t _{PHL} , t _{PLH}	A	В	V _{CCB} = 1.8V ± 0.15V	2.7	ns
			V _{CCB} = 2.5V ± 0.2V	2.6	
			V _{CCB} = 3.3V ± 0.3V	2.8	
			V _{CCB} = 1.2V	3.6	
			V _{CCB} = 1.5V ± 0.1V	3.1	
PHL, [†] PLH	В	Α	V _{CCB} = 1.8V ± 0.15V	2.8	ns
			V _{CCB} = 2.5V ± 0.2V	2.6	
			V _{CCB} = 3.3V ± 0.3V	2.6	
			V _{CCB} = 1.2V	5.6	
i _{PHZ} , t _{PLZ}	ŌĒ	A	V _{CCB} = 1.5V ± 0.1V	4.7	ns
			V _{CCB} = 1.8V ± 0.15V	4.3	
			V _{CCB} = 2.5V ± 0.2V	3.9	
			V _{CCB} = 3.3V ± 0.3V	3.7	
			V _{CCB} = 1.2V	5	
			V _{CCB} = 1.5V ± 0.1V	4.3	
t _{PZH}	ŌĒ	В	V _{CCB} = 1.8V ± 0.15V	3.9	
			V _{CCB} = 2.5V ± 0.2V	3.6	
			V _{CCB} = 3.3V ± 0.3V	36.6	
			V _{CCB} = 1.2V	5	ns
			V _{CCB} = 1.5V ± 0.1V	4.3	
t_{PZL}	ŌĒ	В	V _{CCB} = 1.8V ± 0.15V	3.9	
			V _{CCB} = 2.5V ± 0.2V	3.6	
			V _{CCB} = 3.3V ± 0.3V	3.6	
			V _{CCB} = 1.2V	6.2	
			V _{CCB} = 1.5V ± 0.1V	5.2	ns
t _{PHZ} , t _{PLZ}	ŌĒ	ŌĒ A	V _{CCB} = 1.8V ± 0.15V	5.2	
			V _{CCB} = 2.5V ± 0.2V	4.3	
			V _{CCB} = 3.3V ± 0.3V	4.8	

Product Folder Links: SN74AVC4T245-Q1



5.6 Switching Characteristics: V_{CCA} = 1.2V (continued)

over recommended operating ambient temperature range, V_{CCA} = 1.2V (unless otherwise noted) (see Figure 6-1)

PARAMETER	FROM (INPUT)	TO (OUTPUT) V _{CCB}		TYP	UNIT
			V _{CCB} = 1.2V	5.9	
			$V_{CCB} = 1.5V \pm 0.1V$	5.1	
t _{PHZ} , t _{PLZ}	ŌĒ	В	V _{CCB} = 1.8V ± 0.15V	5	ns
			V _{CCB} = 2.5V ± 0.2V	4.7	
			$V_{CCB} = 3.3V \pm 0.3V$	5.5	

5.7 Switching Characteristics, $V_{CCA} = 1.5V \pm 0.1V$

over recommended operating ambient temperature range, V_{CCA} = 1.5V ± 0.1V (see Figure 6-1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB}	MIN TYP	MAX	UNIT
			V _{CCB} = 1.2V	3.2		
			V _{CCB} = 1.5V ± 0.1V		11.3	
t _{PLH} , t _{PHL}	Α	В	V _{CCB} = 1.8V ± 0.15V		10.2	ns
			$V_{CCB} = 2.5V \pm 0.2V$		9.2	
			$V_{CCB} = 3.3V \pm 0.3V$		9.2	
			V _{CCB} = 1.2V	3.3		
			V _{CCB} = 1.5V ± 0.1V		11.3	
_{PLH} , t _{PHL}	В	Α	V _{CCB} = 1.8V ± 0.15V		11	ns
			$V_{CCB} = 2.5V \pm 0.2V$		10.7	
			$V_{CCB} = 3.3V \pm 0.3V$		10.6	
			V _{CCB} = 1.2V	4.9		
	ŌĒ	А	V _{CCB} = 1.5V ± 0.1V		14.6	
_{PZH} , t _{PZL}			V _{CCB} = 1.8V ± 0.15V		14.5	ns
			$V_{CCB} = 2.5V \pm 0.2V$		14.4	
			$V_{CCB} = 3.3V \pm 0.3V$		14.4	
		В	V _{CCB} = 1.2V	4.5		
	ŌĒ		V _{CCB} = 1.5V ± 0.1V		14.6	
_{PZH} , t _{PZL}			V _{CCB} = 1.8V ± 0.15V		12.7	ns
			$V_{CCB} = 2.5V \pm 0.2V$		10.8	
			$V_{CCB} = 3.3V \pm 0.3V$		10.6	
			V _{CCB} = 1.2V	5.6		
			V _{CCB} = 1.5V ± 0.1V		15.2	
_{PZH} , t _{PZL}	ŌĒ	Α	V _{CCB} = 1.8V ± 0.15V		15.2	ns
			$V_{CCB} = 2.5V \pm 0.2V$		15.2	
			$V_{CCB} = 3.3V \pm 0.3V$		15.2	
			V _{CCB} = 1.2V	5.2		
			V _{CCB} = 1.5V ± 0.1V		15.3	
_{PZH} , t _{PZL}	ŌĒ	В	V _{CCB} = 1.8V ± 0.15V		14.1	ns
			V _{CCB} = 2.5V ± 0.2V		12.4	
			$V_{CCB} = 3.3V \pm 0.3V$		12.6	



5.8 Switching Characteristics: $V_{CCA} = 1.8V \pm 0.15V$

over recommended operating ambient temperature range, $V_{CCA} = 1.8V \pm 0.15V$ (see Figure 6-1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB}	MIN	TYP	MAX	UNIT
			V _{CCB} = 1.2V		2.9		
			V _{CCB} = 1.5V ± 0.1V			11	
t _{PLH} , t _{PHL}	Α	В	V _{CCB} = 1.8V ± 0.15V			9.9	ns
			$V_{CCB} = 2.5V \pm 0.2V$			8.9	
			$V_{CCB} = 3.3V \pm 0.3V$			8.9	
			V _{CCB} = 1.2V		3		
			V _{CCB} = 1.5V ± 0.1V			10.3	
t _{PLH} , t _{PHL}	В	Α	V _{CCB} = 1.8V ± 0.15V			9.9	ns
			$V_{CCB} = 2.5V \pm 0.2V$			9.6	
			$V_{CCB} = 3.3V \pm 0.3V$			9.5	
			V _{CCB} = 1.2V		4.4		
	ŌĒ	А	V _{CCB} = 1.5V ± 0.1V			12.4	ns
t _{PZH} , t _{PZL}			V _{CCB} = 1.8V ± 0.15V			12.3	
			$V_{CCB} = 2.5V \pm 0.2V$			12.3	
			$V_{CCB} = 3.3V \pm 0.3V$			12.2	
			V _{CCB} = 1.2V		4.1		ns
	ŌĒ		V _{CCB} = 1.5V ± 0.1V			14.2	
t _{PZH} , t _{PZL}		В	V _{CCB} = 1.8V ± 0.15V			12.4	
			V _{CCB} = 2.5V ± 0.2V			10.3	
			$V_{CCB} = 3.3V \pm 0.3V$			9.6	
			V _{CCB} = 1.2V		5.4		
			V _{CCB} = 1.5V ± 0.1V			13.6	
t _{PZH} , t _{PZL}	ŌĒ	Α	V _{CCB} = 1.8V ± 0.15V			13.7	ns
			$V_{CCB} = 2.5V \pm 0.2V$			13.7	
			$V_{CCB} = 3.3V \pm 0.3V$			13.7	
			V _{CCB} = 1.2V		5		
			V _{CCB} = 1.5V ± 0.1V			14.9	
t _{PZH} , t _{PZL}	ŌĒ	В	V _{CCB} = 1.8V ± 0.15V			13.7	ns
			V _{CCB} = 2.5V ± 0.2V			11.9	
			V _{CCB} = 3.3V ± 0.3V			11.9	

5.9 Switching Characteristics: $V_{CCA} = 2.5V \pm 0.2V$

over recommended operating ambient temperature range, $V_{CCA} = 2.5V \pm 0.2V$ (see Figure 6-1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB}	MIN TYP	MAX	UNIT
	A	В	V _{CCB} = 1.2V	2.8		
			V _{CCB} = 1.5V ± 0.1V		10.7	
t _{PLH} , t _{PHL}			V _{CCB} = 1.8V ± 0.15V		9.6	ns
			V _{CCB} = 2.5V ± 0.2V		8.5	
			V _{CCB} = 3.3V ± 0.3V		8.6	

Product Folder Links: SN74AVC4T245-Q1



5.9 Switching Characteristics: $V_{CCA} = 2.5V \pm 0.2V$ (continued)

over recommended operating ambient temperature range, V_{CCA} = 2.5V ± 0.2V (see Figure 6-1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB}	MIN	TYP	MAX	UNIT
			V _{CCB} = 1.2V		2.7		
			V _{CCB} = 1.5V ± 0.1V			9.2	
t _{PLH} , t _{PHL}	В	A	V _{CCB} = 1.8V ± 0.15V			8.9	ns
			V _{CCB} = 2.5V ± 0.2V			8.4	
			V _{CCB} = 3.3V ± 0.3V			8.3	
			V _{CCB} = 1.2V		4		
			V _{CCB} = 1.5V ± 0.1V			11.5	
t _{PZH} , t _{PZL}	ŌĒ	A	V _{CCB} = 1.8V ± 0.15V			10.2	ns
			V _{CCB} = 2.5V ± 0.2V			9.8	
			V _{CCB} = 3.3V ± 0.3V			9.8	
	ŌĒ	В	V _{CCB} = 1.2V		3.8		ns
			V _{CCB} = 1.5V ± 0.1V			13.8	
t _{PZH} , t _{PZL}			V _{CCB} = 1.8V ± 0.15V			12	
			V _{CCB} = 2.5V ± 0.2V			9.8	
			V _{CCB} = 3.3V ± 0.3V			9	
			V _{CCB} = 1.2V		4.7		ns
			V _{CCB} = 1.5V ± 0.1V			13.4	
t _{PHZ} , t _{PLZ}	ŌĒ	A	V _{CCB} = 1.8V ± 0.15V			13.4	
			V _{CCB} = 2.5V ± 0.2V			11.2	
			V _{CCB} = 3.3V ± 0.3V			11.5	
			V _{CCB} = 1.2V		4.5		ns
			V _{CCB} = 1.5V ± 0.1V			14.4	
t _{PHZ} , t _{PLZ}	ŌĒ	В	V _{CCB} = 1.8V ± 0.15V			13.2	
			V _{CCB} = 2.5V ± 0.2V			11.2	
			V _{CCB} = 3.3V ± 0.3V			10.2	

5.10 Switching Characteristics: $V_{CCA} = 3.3V \pm 0.3V$

over recommended operating ambient temperature range, V_{CCA} = 3.3V ± 0.3V (see Figure 6-1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB}	MIN TYP	MAX	UNIT
			V _{CCB} = 1.2V	2.9		
			V _{CCB} = 1.5V ± 0.1V		10.6	
t _{PLH} , t _{PHL}	Α	В	V _{CCB} = 1.8V ± 0.15V		9.5	ns
			V _{CCB} = 2.5V ± 0.2V		8.3	
			$V_{CCB} = 3.3V \pm 0.3V$		7.9	
	В		V _{CCB} = 1.2V	2.6		ns
			V _{CCB} = 1.5V ± 0.1V		9.2	
t _{PLH} , t _{PHL}		A	V _{CCB} = 1.8V ± 0.15V		8.4	
			V _{CCB} = 2.5V ± 0.2V		8	
			$V_{CCB} = 3.3V \pm 0.3V$		7.8	

5.10 Switching Characteristics: $V_{CCA} = 3.3V \pm 0.3V$ (continued)

over recommended operating ambient temperature range, $V_{CCA} = 3.3V \pm 0.3V$ (see Figure 6-1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB}	MIN TYP	MAX	UNIT
			V _{CCB} = 1.2V	3.8		
			V _{CCB} = 1.5V ± 0.1V		13.7	
t _{PHZ} , t _{PLZ}	ŌĒ	A	V _{CCB} = 1.8V ± 0.15V		10.2	ns
			$V_{CCB} = 2.5V \pm 0.2V$		8.8	
			$V_{CCB} = 3.3V \pm 0.3V$		8.8	
			V _{CCB} = 1.2V	3.7		
		В	V _{CCB} = 1.5V ± 0.1V		13.7	
t _{PHZ} , t _{PLZ}	ŌĒ		V _{CCB} = 1.8V ± 0.15V		11.8	ns
			$V_{CCB} = 2.5V \pm 0.2V$		9.7	
			$V_{CCB} = 3.3V \pm 0.3V$		8.8	
	ŌĒ		V _{CCB} = 1.2V	4.8		ns
			V _{CCB} = 1.5V ± 0.1V		14.3	
t _{PHZ} , t _{PLZ}		A	V _{CCB} = 1.8V ± 0.15V		13.3	
			$V_{CCB} = 2.5V \pm 0.2V$		10.6	
			$V_{CCB} = 3.3V \pm 0.3V$		11.6	
			V _{CCB} = 1.2V	5.3		ns
			V _{CCB} = 1.5V ± 0.1V		14.3	
t _{PHZ} , t _{PLZ}	ŌĒ	В	V _{CCB} = 1.8V ± 0.15V		13.1	
			$V_{CCB} = 2.5V \pm 0.2V$		11.4	
			$V_{CCB} = 3.3V \pm 0.3V$		11.2	

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5.11 Operating Characteristics

 $T_A = 25^{\circ}C$

	PARAMETER		TEST CONDITIONS	V _{CCA}	TYP	UNIT
				V _{CCA} = V _{CCB} = 1.2V	1	
			$C_L = 0$,	V _{CCA} = V _{CCB} = 1.5V	1	
		Outputs enabled	f = 10MHz,	V _{CCA} = V _{CCB} = 1.8V	1	
			$t_r = t_f = 1$ ns	V _{CCA} =V _{CCB} = 2.5V	1.5	
	A to B			$V_{CCA} = V_{CCB} = 3.3V$	2	
	Atob			$V_{CCA} = V_{CCB} = 1.2V$		
			$C_L = 0$,	V _{CCA} = V _{CCB} = 1.5V		
		Outputs disabled	f = 10MHz,	$V_{CCA} = V_{CCB} = 1.8V$	1	
			$t_r = t_f = 1$ ns	V _{CCA} =V _{CCB} = 2.5V		
(1)				$V_{CCA} = V_{CCB} = 3.3V$		pF
pdA (1)				V _{CCA} = V _{CCB} = 1.2V	12	ρг
			C _L = 0,	V _{CCA} = V _{CCB} = 1.5V	12.5	
		Outputs enabled	f = 10MHz,	V _{CCA} = V _{CCB} = 1.8V	13	
			$t_r = t_f = 1$ ns	V _{CCA} =V _{CCB} = 2.5V	14	
	D 4= A			V _{CCA} = V _{CCB} = 3.3V	15	
B to	B to A			V _{CCA} = V _{CCB} = 1.2V		
			$C_L = 0$, f = 10MHz, $t_r = t_f = 1ns$	V _{CCA} = V _{CCB} = 1.5V		
		Outputs disabled		V _{CCA} = V _{CCB} = 1.8V	1	
		uisabieu		V _{CCA} =V _{CCB} = 2.5V		
				V _{CCA} = V _{CCB} = 3.3V		
		Outputs enabled		V _{CCA} = V _{CCB} = 1.2V	12	
			$C_L = 0,$ f = 10MHz, $t_r = t_f = 1ns$	V _{CCA} = V _{CCB} = 1.5V	12.5	
				V _{CCA} = V _{CCB} = 1.8V	13	-
				V _{CCA} =V _{CCB} = 2.5V	14	
				V _{CCA} = V _{CCB} = 3.3V	15	
	A to B			V _{CCA} = V _{CCB} = 1.2V		
			$C_L = 0$,	V _{CCA} = V _{CCB} = 1.5V		
		Outputs disabled	f = 10MHz,	V _{CCA} = V _{CCB} = 1.8V	1	
		disabled	$t_r = t_f = 1$ ns	V _{CCA} =V _{CCB} = 2.5V		
(1)				V _{CCA} = V _{CCB} = 3.3V		_
pdB ⁽¹⁾				V _{CCA} = V _{CCB} = 1.2V	1	pF
			$C_L = 0$,	V _{CCA} = V _{CCB} = 1.5V	1	
		Outputs enabled	f = 10MHz,	V _{CCA} = V _{CCB} = 1.8V	1	
B t		Gliabled	$t_r = t_f = 1$ ns	V _{CCA} =V _{CCB} = 2.5V	1	
	D 4 - 4			V _{CCA} = V _{CCB} = 3.3V	2	
	B to A			V _{CCA} = V _{CCB} = 1.2V		
			C _L = 0,	V _{CCA} = V _{CCB} = 1.5V		
		Outputs	$G_L = 0$, $f = 10MHz$,	V _{CCA} = V _{CCB} = 1.8V	1	
		disabled	$t_r = t_f = 1$ ns	V _{CCA} =V _{CCB} = 2.5V		
				V _{CCA} = V _{CCB} = 3.3V		

⁽¹⁾ Power dissipation capacitance per transceiver



5.12 Typical Characteristics

 $T_A = 25^{\circ}C$

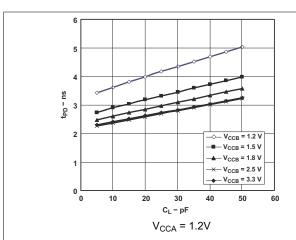


Figure 5-1. Typical Propagation Delay (A to B) vs Load Capacitance

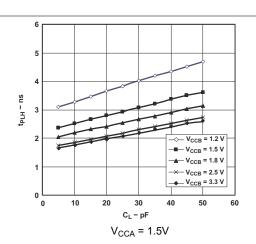


Figure 5-2. Typical Propagation Delay (A to B) vs Load Capacitance

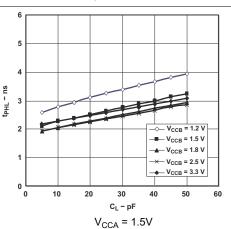


Figure 5-3. Typical Propagation Delay (A to B) vs Load Capacitance

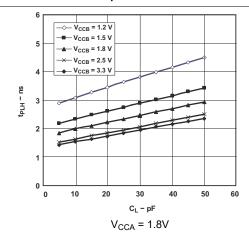


Figure 5-4. Typical Propagation Delay (A to B) vs Load Capacitance

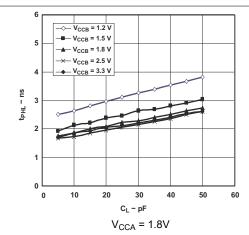


Figure 5-5. Typical Propagation Delay (A to B) vs Load Capacitance

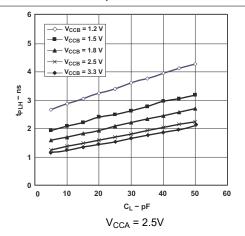


Figure 5-6. Typical Propagation Delay (A to B) vs Load Capacitance

5.12 Typical Characteristics (continued)

 $T_A = 25^{\circ}C$

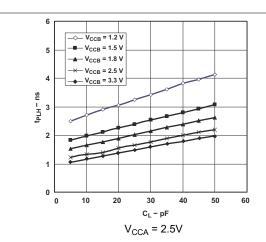


Figure 5-7. Typical Propagation Delay (A to B) vs Load Capacitance

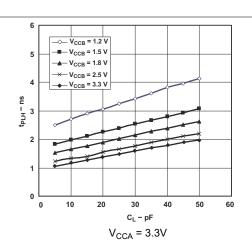


Figure 5-8. Typical Propagation Delay (A to B) vs Load Capacitance

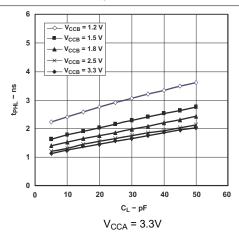


Figure 5-9. Typical Propagation Delay (A to B) vs Load Capacitance

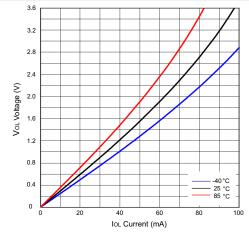


Figure 5-10. Low-Level Output Voltage (V_{OL}) vs Low-Level Current (I_{OL})

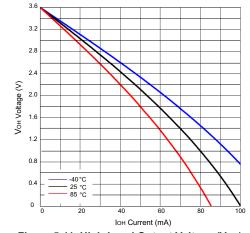
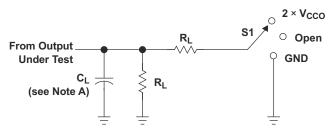


Figure 5-11. High-Level Output Voltage (V_{OH}) vs High-Level Current (I_{OH})



 V_{CCA}

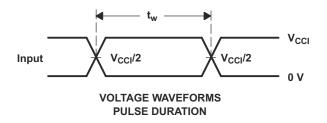
6 Parameter Measurement Information

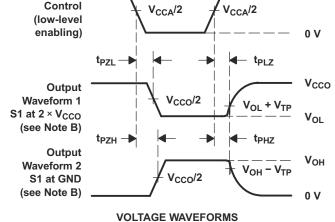


TEST	S1
t _{pd}	Open
t _{PLZ} /t _{PZL}	2 × V _{CCO}
t _{PHZ} /t _{PZH}	GND

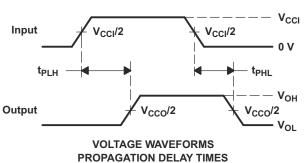
LOAD CIRCUIT

V _{CCO}	CL	R _L	V _{TP}
1.2 V	15 pF	2 k Ω	0.1 V
1.5 V ± 0.1 V	15 pF	2 k Ω	0.1 V
1.8 V ± 0.15 V	15 pF	2 k Ω	0.15 V
2.5 V ± 0.2 V	15 pF	2 k Ω	0.15 V
3.3 V ± 0.3 V	15 pF	2 k Ω	0.3 V





ENABLE AND DISABLE TIMES



NOTES: A. C_L includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.

Output

- C. All input pulses are supplied by generators having the following characteristics: PRR ≤10 MHz, Z_O= 50 Ω, dv/dt ≥ 1 V/ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- $\begin{array}{ll} \text{G.} & t_{PLH} \text{ and } t_{PHL} \text{ are the same as } t_{pd}. \\ \text{H.} & V_{CCI} \text{ is the } V_{CC} \text{ associated with the input port.} \end{array}$
- I. V_{CCO} is the V_{CC} associated with the output port.

Figure 6-1. Load and Circuit and Voltage Waveforms



7 Detailed Description

7.1 Overview

The SN74AVC4T245-Q1 is a 4-bit, dual-supply noninverting bidirectional voltage level translation device. Ax pins and control pins (1DIR, 2DIR,1 \overline{OE} , and 2 \overline{OE}) are supported by V_{CCA}, and Bx pins are supported by V_{CCB}. The A port is able to accept I/O voltages ranging from 1.2V to 3.6V, while the B port can accept I/O voltages from 1.2V to 3.6V. A high on DIR allows data transmission from Ax to Bx and a low on DIR allows data transmission from Bx to Ax when \overline{OE} is set to low. When \overline{OE} is set to high, both Ax and Bx pins are in the high-impedance state.

7.2 Functional Block Diagram

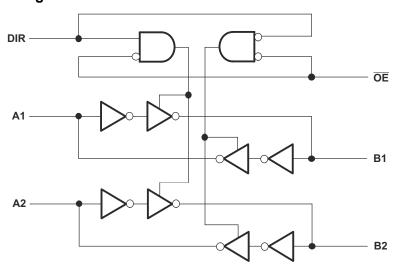


Figure 7-1. Logic Diagram (Positive Logic) for 1/2 of SN74AVC4T245-Q1

7.3 Feature Description

7.3.1 Fully Configurable Dual-Rail Design

Both V_{CCA} and V_{CCB} can be supplied at any voltage between 1.2V and 3.6V; thus, making the device suitable for translating between any of the low voltage nodes (1.2V, 1.8V, 2.5V, and 3.3V).

7.3.2 Supports High Speed Translation

The SN74AVC4T245-Q1 device can support high data rate applications. The translated signal data rate can be up to 380Mbps when the signal is translated from 1.8V to 3.3V.

7.3.3 I_{off} Supports Partial-Power-Down Mode Operation

loff prevents backflow current by disabling I/O output circuits when the device is in partial-power-down mode.

7.4 Device Functional Modes

Table 7-1 lists the functional modes of the SN74AVC4T245-Q1 device.

Table 7-1. Function Table (Each 2-Bit Section)

			, , , , , ,		
CONTROL INPUTS		OUTPUT CIR	CUITS	OPERATION	
ŌĒ	DIR	A PORT	B PORT	OFERATION	
L	L	Enabled	Hi-Z	B data to A bus	
L	Н	Hi-Z	Enabled	A data to B bus	
Н	Х	Hi-Z	Hi-Z	Isolation	

Product Folder Links: SN74AVC4T245-Q1

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8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

The SN74AVC4T245-Q1 device can be used in level-translation applications for interfacing devices or systems operating at different interface voltages with one another. The SN74AVC4T245-Q1 device is ideal for use in applications where a push-pull driver is connected to the data I/Os. The maximum data rate can be up to 380Mbps when the device translates a signal from 1.8V to 3.3V.

8.2 Typical Application

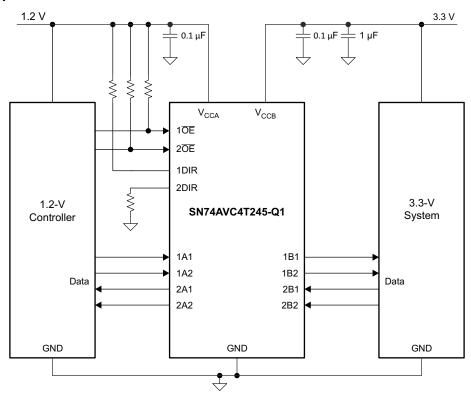


Figure 8-1. Typical Application Diagram

8.2.1 Design Requirements

Table 8-1 lists the parameters for this design example.

Table 8-1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage range	1.2V
Output voltage range	3.3V

8.2.2 Detailed Design Procedure

To begin the design process, determine the following:

- · Input voltage range
 - Use the supply voltage of the device that is driving the SN74AVC4T245-Q1 device to determine the input voltage range. For a valid logic high, the value must exceed the V_{IH} of the input port. For a valid logic low, the value must be less than the V_{IL} of the input port. For this example, the input voltage is 1.2V.
- · Output voltage range
 - Use the supply voltage of the device that the SN74AVC4T245-Q1 device is driving to determine the output voltage range. For this example, the output voltage is 3.3V.

8.2.3 Application Curve

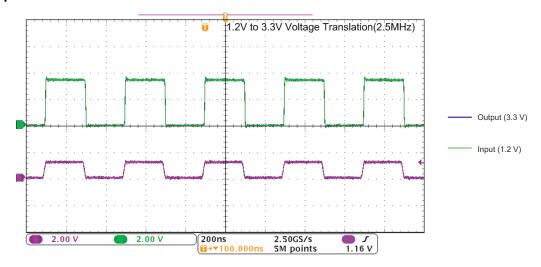


Figure 8-2. Translation Up (1.2V to 3.3V) at 2.5MHz

8.3 Power Supply Recommendations

The SN74AVC4T245-Q1 device uses two separate configurable power-supply rails: V_{CCA} and V_{CCB} . V_{CCA} accepts any supply voltage from 1.2V to 3.6V, and V_{CCB} accepts any supply voltage from 1.2V to 3.6V. The A port and B port are designed to track V_{CCA} and V_{CCB} respectively, allowing for low-voltage bidirectional translation between any of the 1.2V, 1.5V, 1.8V, 2.5V, and 3.3V voltage nodes.

The output-enable (\overline{OE}) input circuit is designed so that it is supplied by V_{CCA} ; when the \overline{OE} input is high, all outputs are placed in the high-impedance state. To place the outputs in the high-impedance state during power up or power down, tie the \overline{OE} input pin to V_{CCA} through a pullup resistor and do not enable it until V_{CCA} and V_{CCB} are fully ramped and stable. The minimum value of the pullup resistor to V_{CCA} is determined by the current-sinking capability of the driver.

Product Folder Links: SN74AVC4T245-Q1

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8.4 Layout

8.4.1 Layout Guidelines

For device reliability, it is recommended to follow common printed-circuit board layout guidelines such as:

- Use bypass capacitors on power supplies.
- · Use short trace lengths to avoid excessive loading.
- Place pads on the signal paths for loading capacitors or pullup resistors to help adjust rise and fall times of signals, depending on the system requirements.

8.4.2 Layout Example

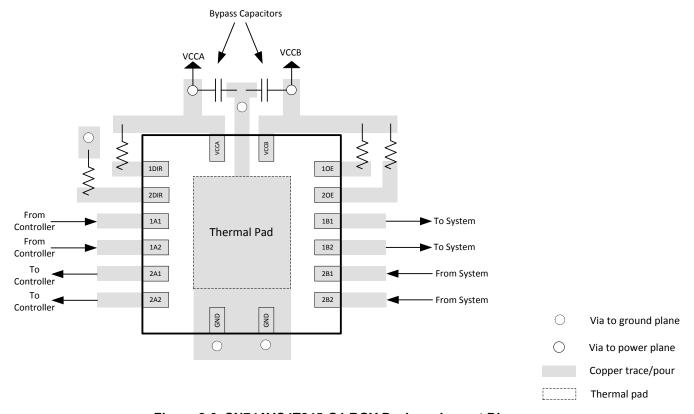


Figure 8-3. SN74AVC4T245-Q1 RGY Package Layout Diagram



9 Device and Documentation Support

9.1 Documentation Support

9.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, IC Package Thermal Metrics
- Texas Instruments, Implications of Slow or Floating CMOS Inputs

9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.3 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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9.4 Trademarks

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9.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.6 Glossary

TI Glossarv

This glossary lists and explains terms, acronyms, and definitions.

10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

C	Changes from Revision B (March 2016) to Revision C (February 2024)	Page
•	Added Functional safety link to Features list	1
•	Updated the Package Information table to include package lead size	1
•	Added the PW, BQB, and DYY packages	1

Changes	from Revision A (October 2012) to Revision B (October 2015)	Page
 Added 	Applications section	1
	I -Q1 to the part number throughout the data sheet	
	Device Information table to the data sheet	
	ed Ordering Information table from the data sheet	
 Added 	I Pin Functions table to the data sheet	3
 Added 	I ESD Ratings table to the data sheet	5
 Added 	I Thermal Information table to the data sheet	6
	I Typical Characteristics section to the data sheet	
	••	

Product Folder Links: SN74AVC4T245-Q1

	INSTRUMENTS
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•	Added Figure 5-1 through Figure 5-9 to the Section 5.12 section	14
•	Added all new content from Section 8.1 through the end of the data sheet	17
С	hanges from Revision * (November 2009) to Revision A (October 2012)	Page
_	hanges from Revision * (November 2009) to Revision A (October 2012) Added AEC-Q100 info to Features	
•	• • • • • • • • • • • • • • • • • • • •	1

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the mostcurrent data available for the designated device. This data is subject to change without notice and without revision of this document. For browser-based versions of this data sheet, see the left-hand navigation pane.

www.ti.com 9-Nov-2025

PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
	(1)	(2)			(3)	(4)	(5)		(0)
74AVC4T245QDYYRQ1	Active	Production	SOT-23-THIN (DYY) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	WT245Q
74AVC4T245QDYYRQ1.A	Active	Production	SOT-23-THIN (DYY) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	WT245Q
74AVC4T245QPWRQ1	Active	Production	TSSOP (PW) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	WT245Q
74AVC4T245QPWRQ1.A	Active	Production	TSSOP (PW) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	WT245Q
74AVC4T245QRGYRQ1	Active	Production	VQFN (RGY) 16	3000 LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 125	4T245Q
74AVC4T245QRGYRQ1.A	Active	Production	VQFN (RGY) 16	3000 LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 125	4T245Q
74AVC4T245QRGYRQ1.B	Active	Production	VQFN (RGY) 16	3000 LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 125	4T245Q
74AVC4T245QWBQBRQ1	Active	Production	WQFN (BQB) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	WT245Q
74AVC4T245QWBQBRQ1.A	Active	Production	WQFN (BQB) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	WT245Q
74AVC4T245RGYRQ1G4	Active	Production	VQFN (RGY) 16	3000 LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 125	4T245Q
74AVC4T245RGYRQ1G4.A	Active	Production	VQFN (RGY) 16	3000 LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 125	4T245Q
74AVC4T245RGYRQ1G4.B	Active	Production	VQFN (RGY) 16	3000 LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 125	4T245Q

⁽¹⁾ Status: For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



PACKAGE OPTION ADDENDUM

www.ti.com 9-Nov-2025

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF SN74AVC4T245-Q1:

Catalog: SN74AVC4T245

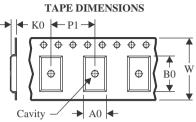
NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

www.ti.com 24-Jul-2025

TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
74AVC4T245QDYYRQ1	SOT-23- THIN	DYY	16	3000	330.0	12.4	4.8	3.6	1.6	8.0	12.0	Q3
74AVC4T245QPWRQ1	TSSOP	PW	16	3000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
74AVC4T245QRGYRQ1	VQFN	RGY	16	3000	330.0	12.4	3.8	4.3	1.5	8.0	12.0	Q1
74AVC4T245QWBQBRQ1	WQFN	BQB	16	3000	180.0	12.4	2.8	3.8	1.2	4.0	12.0	Q1
74AVC4T245RGYRQ1G4	VQFN	RGY	16	3000	330.0	12.4	3.8	4.3	1.5	8.0	12.0	Q1



www.ti.com 24-Jul-2025



*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
74AVC4T245QDYYRQ1	SOT-23-THIN	DYY	16	3000	336.6	336.6	31.8
74AVC4T245QPWRQ1	TSSOP	PW	16	3000	353.0	353.0	32.0
74AVC4T245QRGYRQ1	VQFN	RGY	16	3000	353.0	353.0	32.0
74AVC4T245QWBQBRQ1	WQFN	BQB	16	3000	210.0	185.0	35.0
74AVC4T245RGYRQ1G4	VQFN	RGY	16	3000	353.0	353.0	32.0

2.5 x 3.5, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



INSTRUMENTS www.ti.com

INDSTNAME



NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.



INDSTNAME



NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



INDSTNAME



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



PLASTIC SMALL OUTLINE



NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per side
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- 5. Reference JEDEC Registration MO-345, Variation AA



PLASTIC SMALL OUTLINE



NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PLASTIC SMALL OUTLINE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- G. Package complies to JEDEC MO-241 variation BA.



RGY (R-PVQFN-N16)

PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

4206353-3/P 03/14

NOTE: All linear dimensions are in millimeters



RGY (R-PVQFN-N16)

PLASTIC QUAD FLATPACK NO-LEAD



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



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